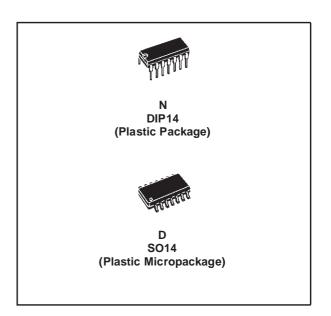


WIDE BANDWIDTH QUAD J-FET OPERATIONAL AMPLIFIERS

- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO V_{CC}⁺) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT **STAGE**
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE: 16V/µs (typ)



DESCRIPTION

These circuits are high speed J-FET input quad operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

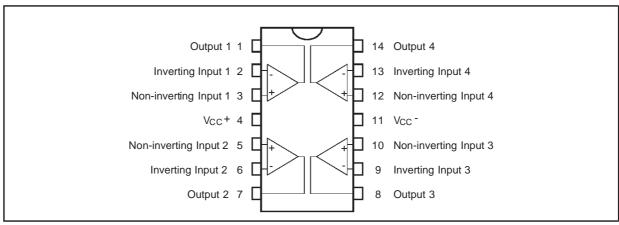
The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

ORDER CODE

Part Number	Temperature Range	Package				
	Temperature Name	N	D			
LF147	-55°C, +125°C	•	•			
LF247	-40°C, +105°C	•	•			
LF347	0°C, +70°C	•	•			
Example: LF347IN						

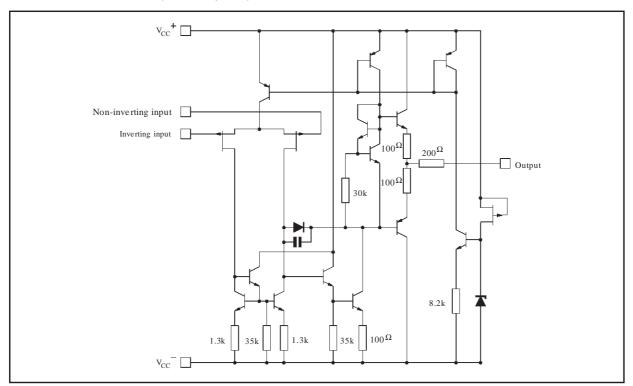
N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

PIN CONNECTIONS (top view)



March 2001 1/10

SCHEMATIC DIAGRAM (each amplifier)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LF147	LF247	LF347	Unit
V _{CC}	Supply voltage - note 1)	±18			V
Vi	Input Voltage - note ²⁾	±15			V
V_{id}	Differential Input Voltage - note 3)	±30			V
P _{tot}	Power Dissipation	680			mW
	Output Short-circuit Duration - note 4)	Infinite			
T _{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T _{stg}	Storage Temperature Range	-65 to +150			°C

All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}.

^{2.} The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

^{3.} Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

^{4.} The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

ELECTRICAL CHARACTERISTICS

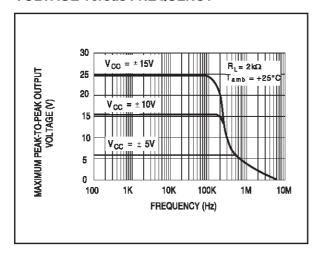
 $V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Input Offset Voltage ($R_s = 10k\Omega$)				mV
V_{io}	$T_{amb} = 25^{\circ}C$		3	10	
	$T_{min} \le T_{amb} \le T_{max}$			13	
DV _{io}	Input Offset Voltage Drift		10		μV/°C
	Input Offset Current - note 1)				
I_{io}	$T_{amb} = 25^{\circ}C$		5	100	pА
	$T_{min} \le T_{amb} \le T_{max}$			4	nA
	Input Bias Current - note 1				
I_{ib}	$T_{amb} = 25^{\circ}C$		20	200	pА
	$T_{min} \le T_{amb} \le T_{max}$			20	nA
	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$,				V/mV
A_{vd}	$T_{amb} = 25^{\circ}C$	50	200		
	$T_{min} \le T_{amb} \le T_{max}$	25			
	Supply Voltage Rejection Ratio ($R_S = 10k\Omega$)				dB
SVR	$T_{amb} = 25^{\circ}C$	80	86		
	$T_{min} \le T_{amb} \le T_{max}$	80			
	Supply Current, Per Amp, no Load				mA
I_{CC}	T _{amb} = 25°C		1.4	2.7	
	$T_{min} \le T_{amb} \le T_{max}$			2.7	
V _{icm}	Input Common Mode Voltage Range	±11	+15 -12		V
	Common Mode Rejection Ratio ($R_S = 10k\Omega$)				dB
CMR	$T_{amb} = 25^{\circ}C$	70	86		d B
	$T_{min} \le T_{amb} \le T_{max}$	70			
	Output Short-Circuit Current				mA
Ios	$T_{amb} = 25^{\circ}C$	10	40	60	
	$T_{min} \le T_{amb} \le T_{max}$	10		60	
	Output Voltage Swing				V
	$T_{amb} = 25^{\circ}C$ $R_L = 2k\Omega$	10	12		ľ
$\pm V_{opp}$	$R_L = 10k\Omega$	12	13.5		
	$T_{min} \le T_{amb} \le T_{max}$ $R_L = 2k\Omega$	10			
	$R_L = 10k\Omega$	12			
SR	Slew Rate	40	4.0		V/μs
	$V_i = 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain	12	16		
t _r	Rise Time $V_i = 20\text{mV}, R_L = 2\text{k}\Omega, C_L = 100\text{pF}, T_{amb} = 25^{\circ}\text{C}, \text{ unity gain}$		0.1		μs
	Overshoot		0.1		%
K_{ov}	$V_i = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, $T_{amb} = 25$ °C, unity gain		10		/0
	Gain Bandwidth Product				MHz
GBP	$f = 100kHz$, $T_{amb} = 25^{\circ}C$, $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$	2.5	4		1711 12
R _i	Input Resistance		10 ¹²		Ω
	Total Harmonic Distortion		10		%
THD	$f = 1 \text{kHz}$, $A_v = 20 \text{dB}$, $R_L = 2 \text{k}\Omega$, $C_L = 100 \text{pF}$				/0
	$T_{amb} = 25^{\circ}C$, $V_{O} = 2Vpp$		0.01		
					nV
e_n	Equivalent Input Noise Voltage ($R_S = 100\Omega$, $f = 1KHz$)		15		<u>nV</u> √Hz
(X ===	Phone Marain		A F		· ·
Øm	Phase Margin Channel Separation (A _v = 100)		45		Degrees
V_{o1}/V_{o2}	Onamiei Separation (A _V = 100)		120		dB

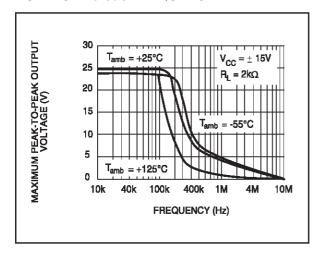
^{1.} The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.



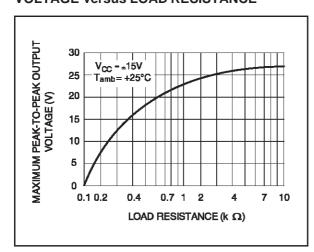
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



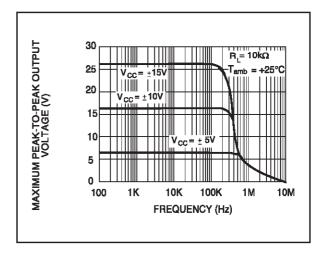
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



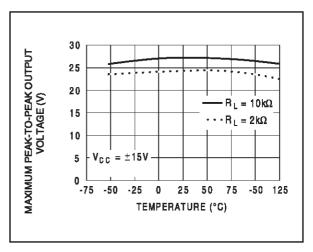
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



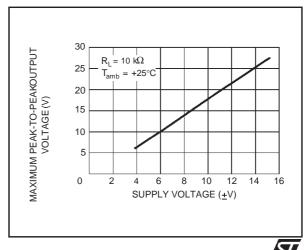
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



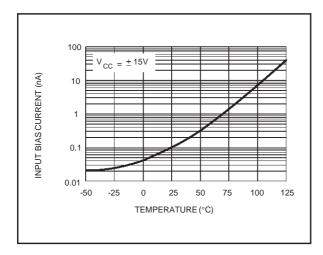
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.



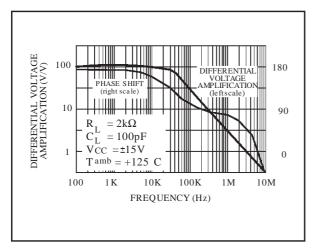
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE



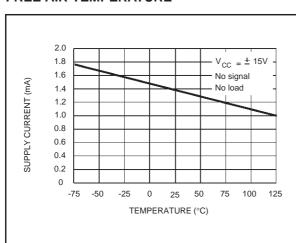
INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



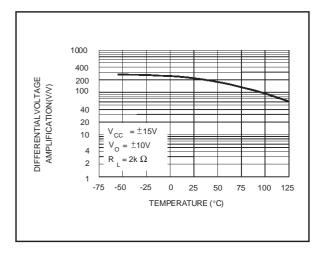
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



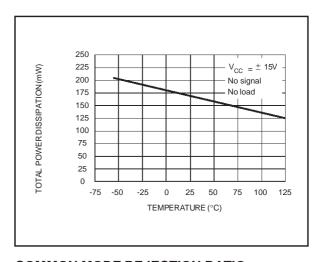
SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



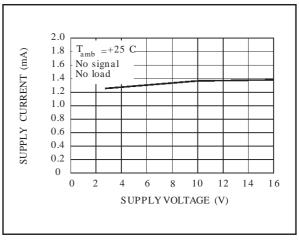
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



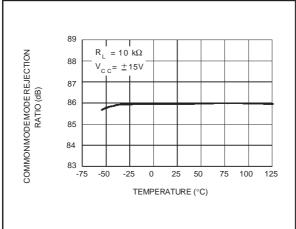
TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



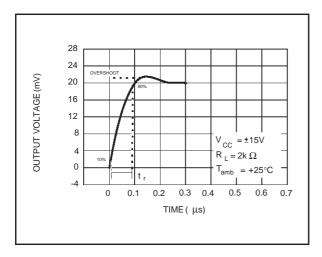
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



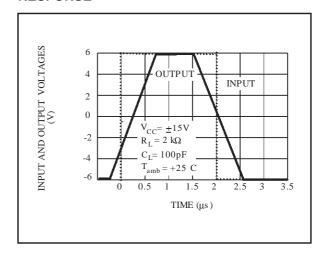
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



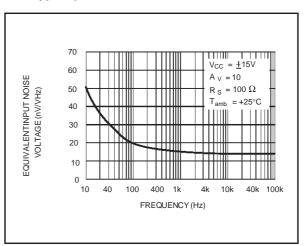
OUTPUT VOLTAGE versus ELAPSED TIME



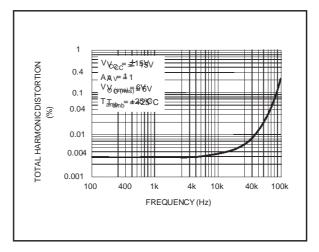
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



TOTAL HARMONIC DISTORTION versus FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

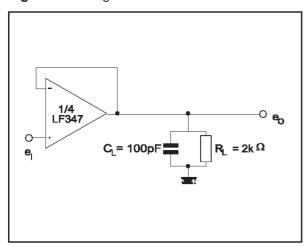
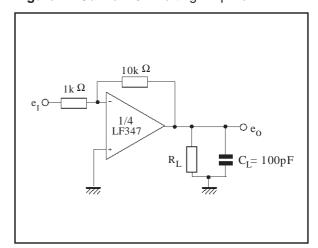
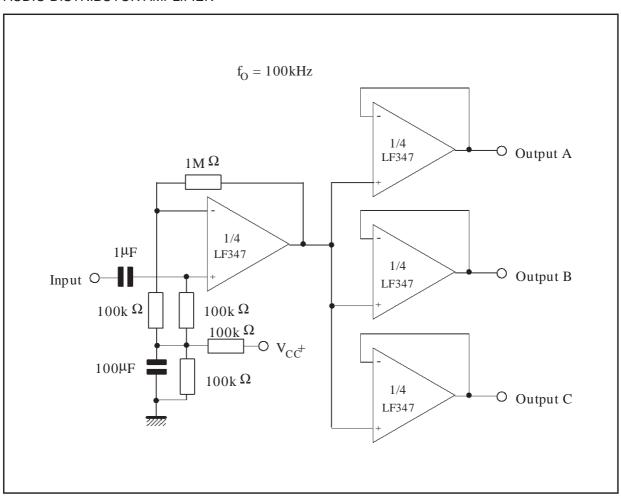


Figure 2: Gain-of-10 Inverting Amplifier

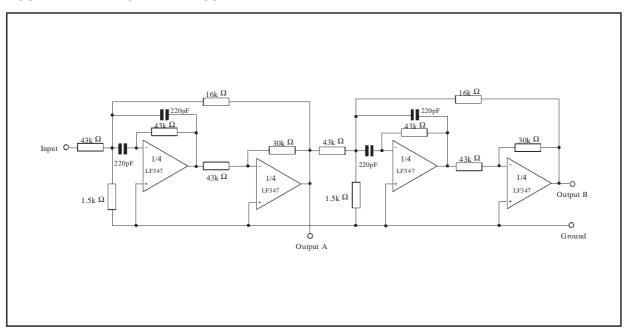


TYPICAL APPLICATIONS
AUDIO DISTRIBUTOR AMPLIFIER

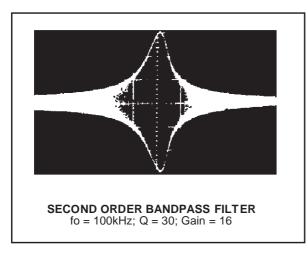


TYPICAL APPLICATIONS (continued)

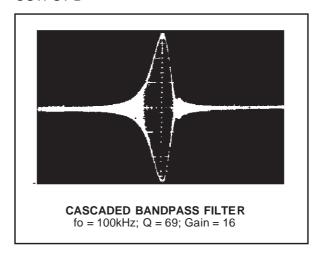
POSITIVE FEEDBACK BANDPASS FILTER



OUTPUT A



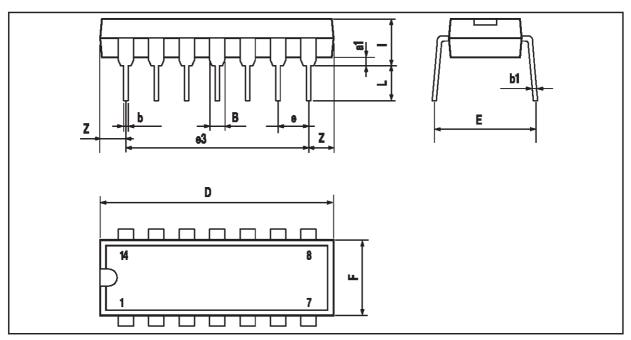
OUTPUT B



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PACKAGE MECHANICAL DATA

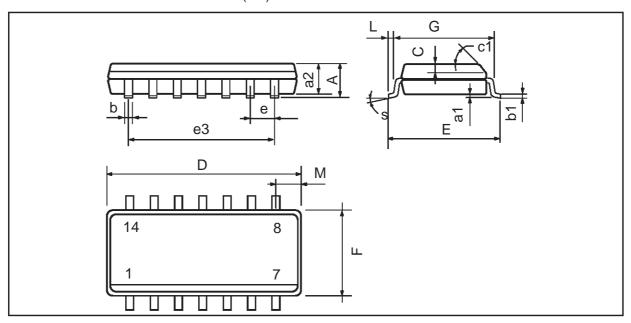
14 PINS - PLASTIC DIP



Dim.	Millimeters		Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.
a1	0.51			0.020		
В	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.020	
c1			45°	(typ.)		
D (1)	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		7.62			0.300	
F (1)	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
М			0.68			0.027
S	8° (max.)					

Note: (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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